

## Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C
40V	0.7mΩ @ V <sub>GS</sub> = 10V	584A

## Description and Applications


This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

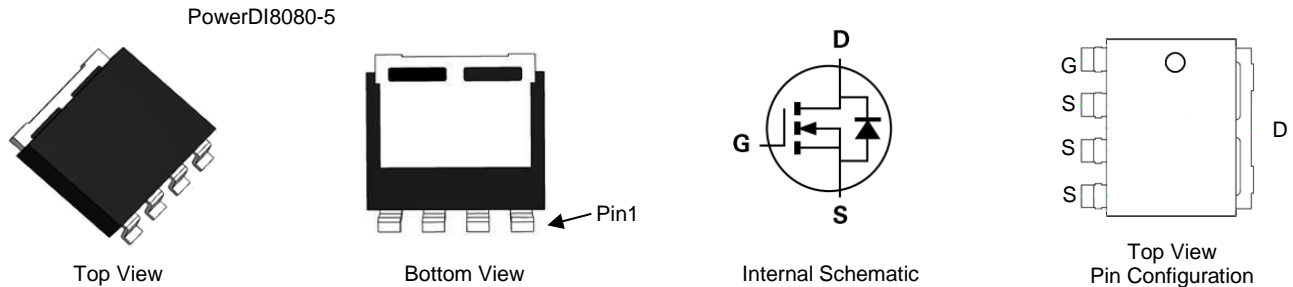
- Engine management systems
- Body control electronics
- DC-DC converters

## Features and Benefits

- Rated to +175°C — Ideal for High Ambient Temperature Environments
  - 100% Unclamped Inductive Switching (UIS) Test in Production — Ensures More Reliable and Robust End Application
  - High Conversion Efficiency
  - Low R<sub>DS(ON)</sub> — Minimizes Power Losses
  - Wettable Flank for Improved Optical Inspection
  - Fast Switching Speed
  - Low Input Capacitance
  - **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
  - **Halogen and Antimony Free. "Green" Device (Note 3)**
  - The DMTH4M72SPGWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.
- <https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

- Package: PowerDI<sup>®</sup>8080-5
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 
- Weight: 0.33 grams (Approximate)

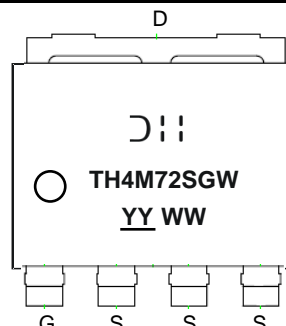


## Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
DMTH4M72SPGWQ-13	PowerDI8080-5	2000	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



D = Manufacturer's Marking  
TH4M72SGW = Product Type Marking Code  
YYWW = Date Code Marking  
YY = Year (ex: 25 = 2025)  
WW = Week (01 to 53)

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**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6)	T <sub>C</sub> = +25°C	I <sub>D</sub>	584	A
	T <sub>C</sub> = +100°C		413	
Maximum Continuous Body Diode Forward Current (Note 6)		I <sub>S</sub>	584	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	2336	A
Pulsed Body Diode Forward Current (10μs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	2336	A
Avalanche Current, L = 1mH		I <sub>AS</sub>	41.6	A
Avalanche Energy, L = 1mH		E <sub>AS</sub>	865	mJ

**Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	P <sub>D</sub>	5.6	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>θJA</sub>	27	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	P <sub>D</sub>	441	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>θJC</sub>	0.34	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b> (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	—	—	V	V <sub>GS</sub> = 0, I <sub>D</sub> = 1mA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0
<b>ON CHARACTERISTICS</b> (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	—	4	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	0.5	0.7	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 25A
Diode Forward Voltage	V <sub>SD</sub>	—	0.7	1.2	V	V <sub>GS</sub> = 0, I <sub>S</sub> = 20A
<b>DYNAMIC CHARACTERISTICS</b> (Note 8)						
Input Capacitance	C <sub>iss</sub>	—	9522	—	pF	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0, f = 1MHz
Output Capacitance	C <sub>oss</sub>	—	5410	—		
Reverse Transfer Capacitance	C <sub>rss</sub>	—	173	—		
Gate Resistance	R <sub>g</sub>	—	2.1	—	Ω	V <sub>DS</sub> = 0, V <sub>GS</sub> = 0, f = 1MHz
Total Gate Charge	Q <sub>g</sub>	—	118	—	nC	V <sub>DD</sub> = 20V, I <sub>D</sub> = 25A, V <sub>GS</sub> = 10V
Gate-Source Charge	Q <sub>gs</sub>	—	45	—		
Gate-Drain Charge	Q <sub>gd</sub>	—	9.4	—		
Turn-On Delay Time	t <sub>D(ON)</sub>	—	33	—	ns	V <sub>DD</sub> = 20V, V <sub>GS</sub> = 10V, I <sub>D</sub> = 25A, R <sub>G</sub> = 5Ω
Turn-On Rise Time	t <sub>r</sub>	—	45	—		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	122	—		
Turn-Off Fall Time	t <sub>f</sub>	—	58	—		
Body Diode Reverse-Recovery Time	t <sub>RR</sub>	—	81	—	ns	I <sub>F</sub> = 25A, di/dt = 100A/μs
Body Diode Reverse-Recovery Charge	Q <sub>RR</sub>	—	172	—	nC	

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
  - Thermal resistance from junction to soldering point (on the exposed drain pad).
  - Short duration pulse test used to minimize self-heating effect.
  - Guaranteed by design. Not subject to product testing.

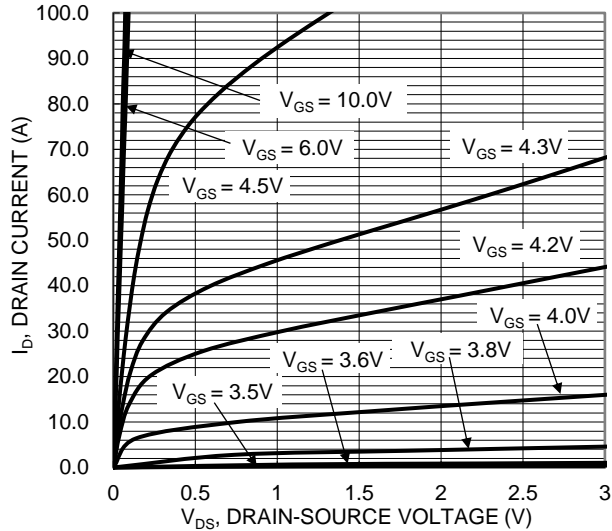


Figure 1. Typical Output Characteristic

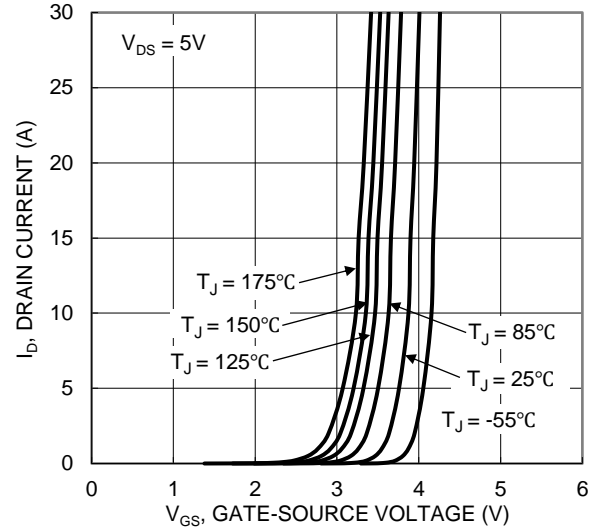


Figure 2. Typical Transfer Characteristic

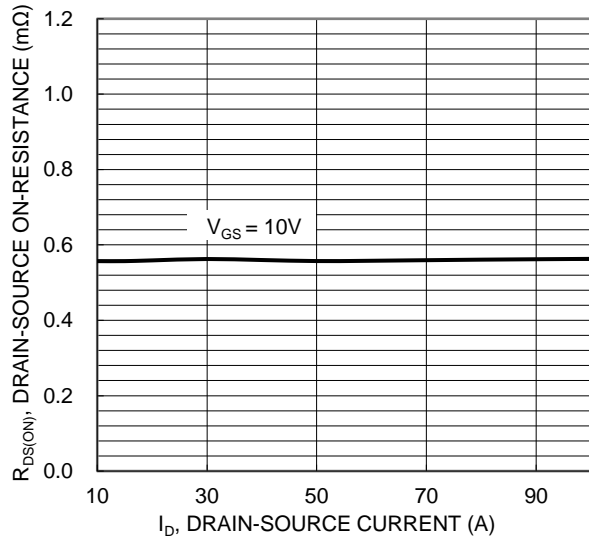


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

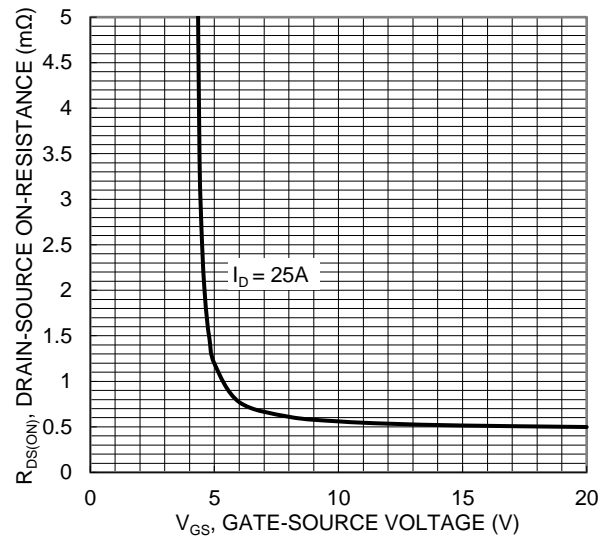


Figure 4. Typical Transfer Characteristic

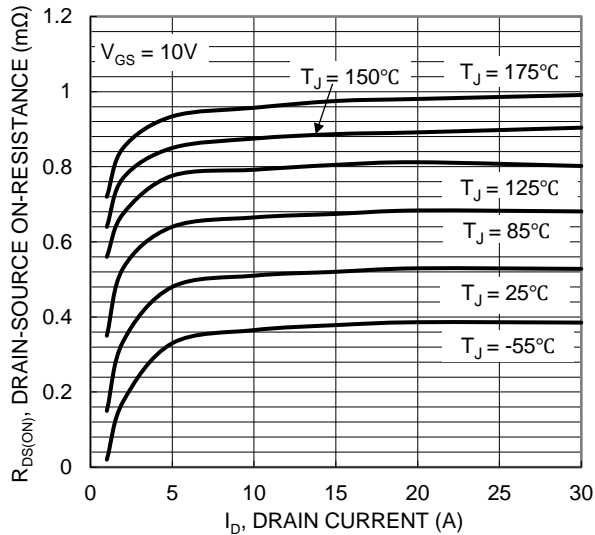


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

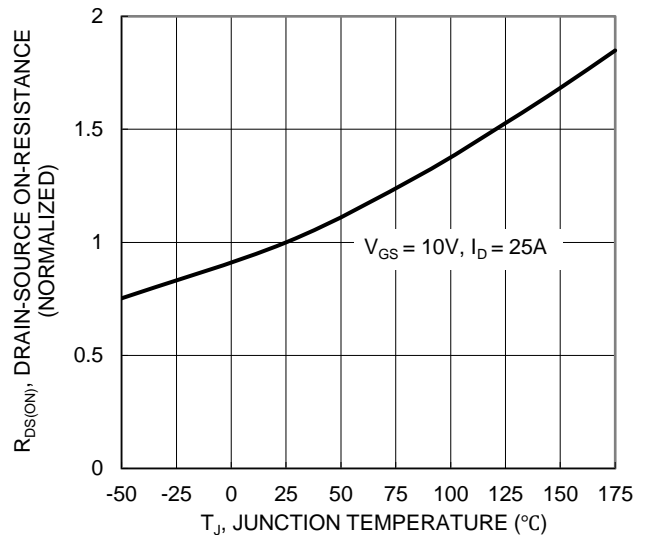


Figure 6. On-Resistance Variation with Junction Temperature

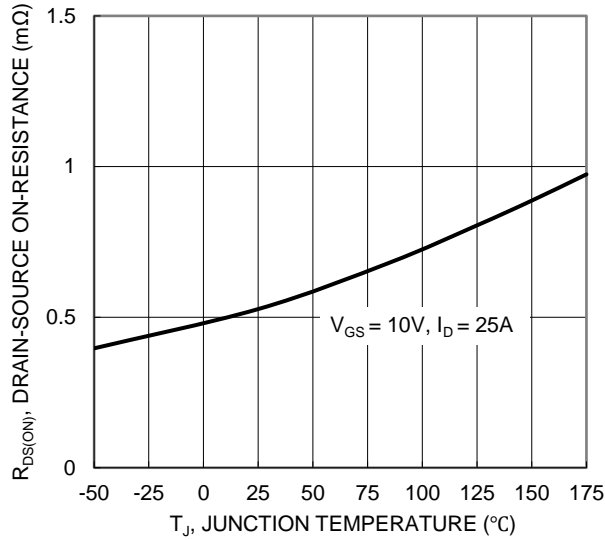


Figure 7. On-Resistance Variation with Junction Temperature

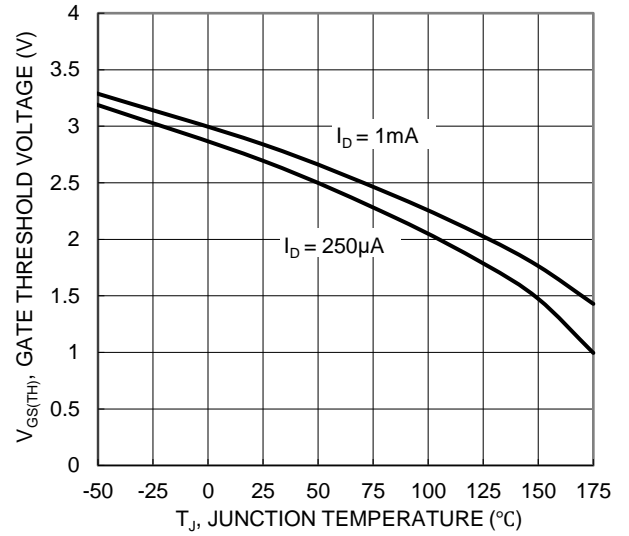


Figure 8. Gate Threshold Variation vs. Junction Temperature

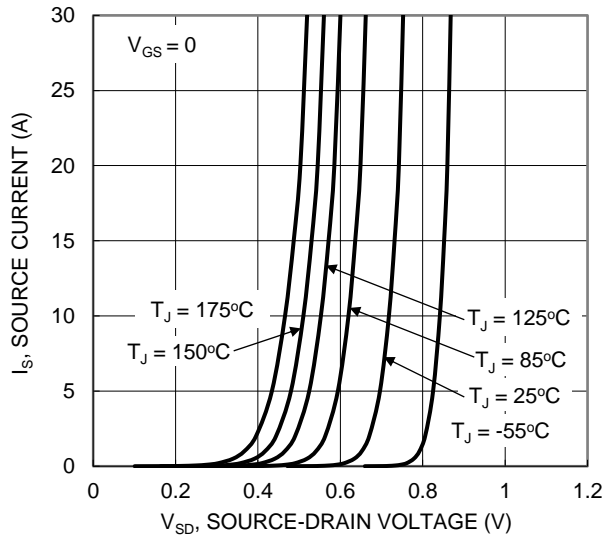


Figure 9. Diode Forward Voltage vs. Current

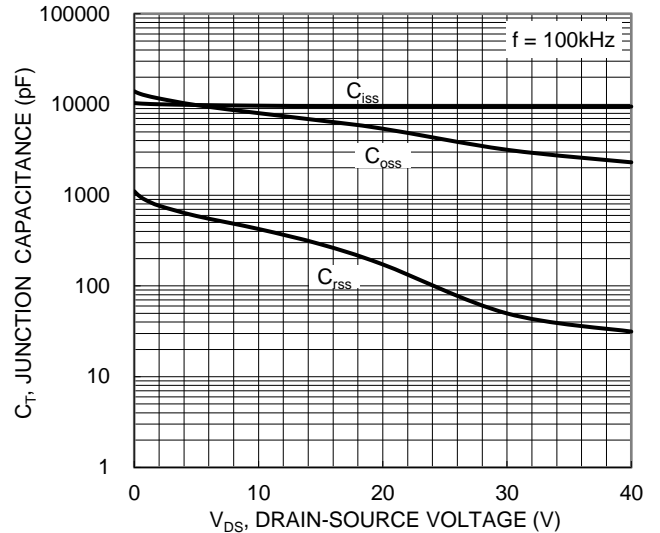


Figure 10. Typical Junction Capacitance

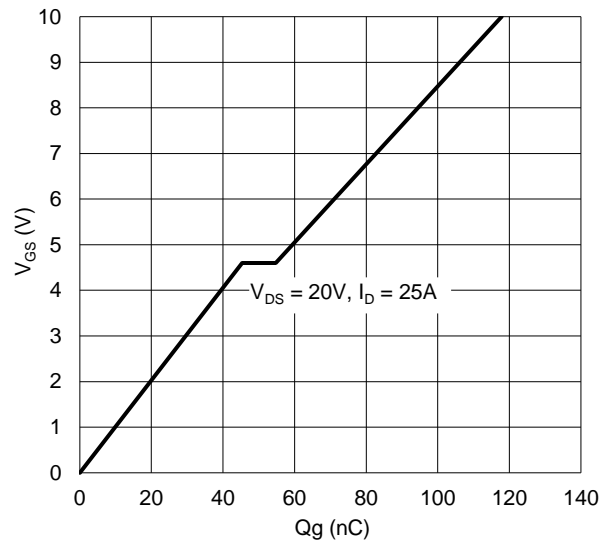


Figure 11. Gate Charge

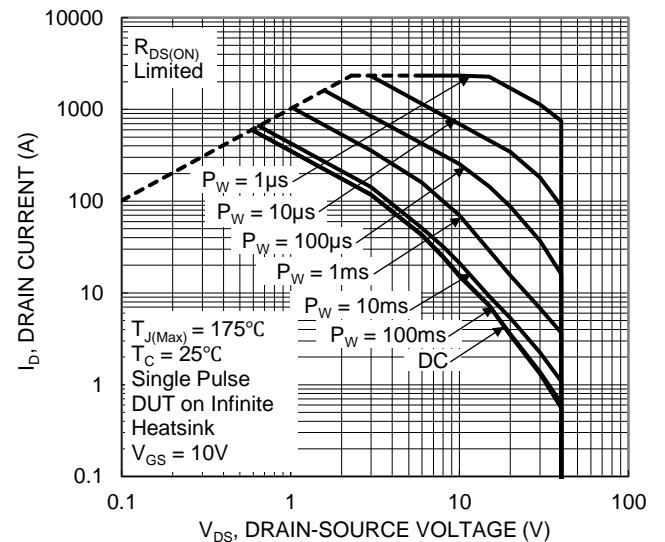


Figure 12. SOA, Safe Operation Area

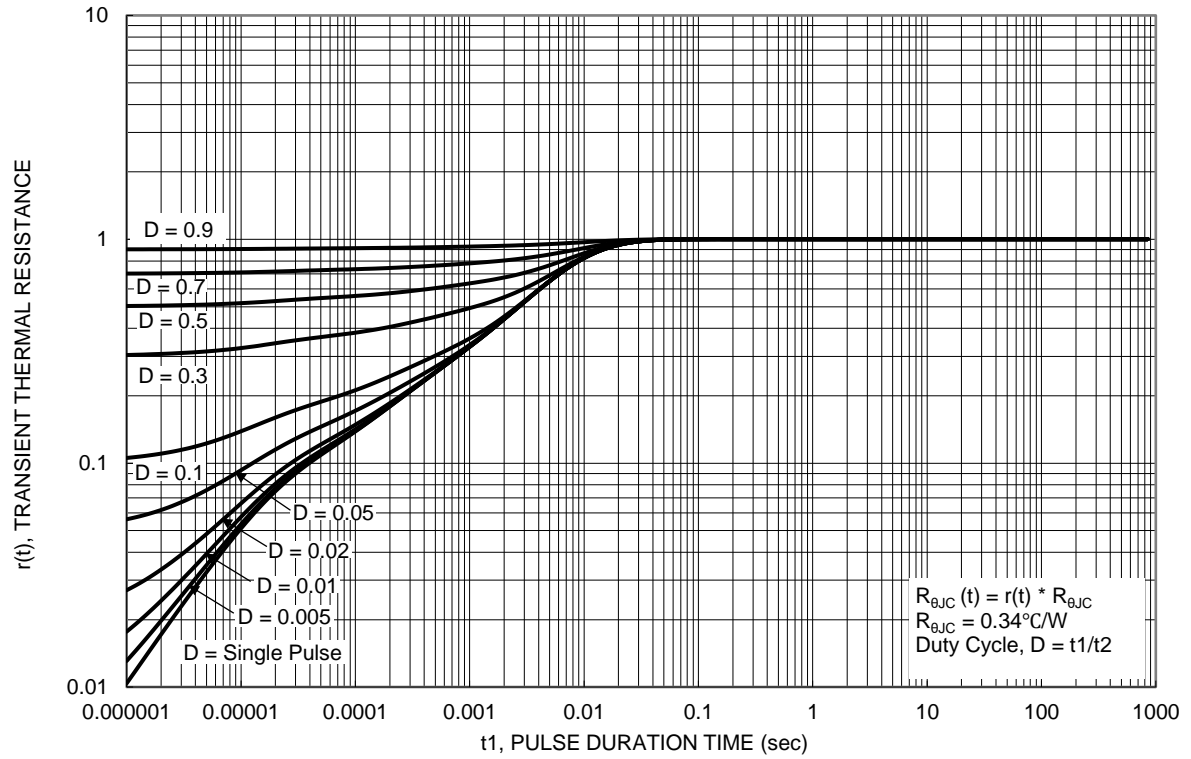
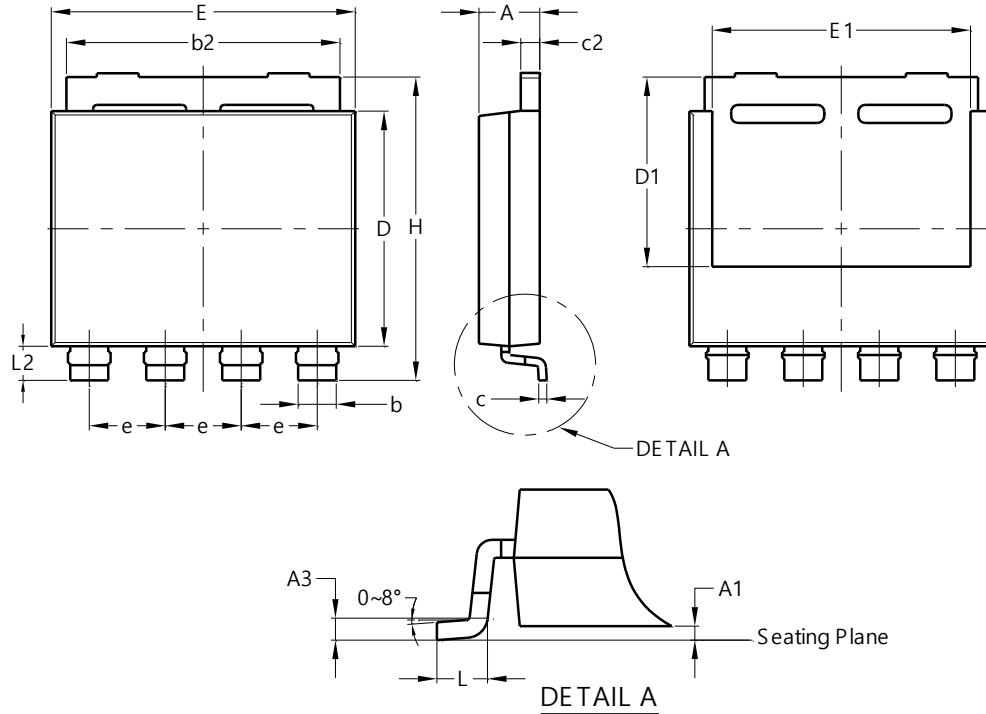


Figure 13. Transient Thermal Resistance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI8080-5

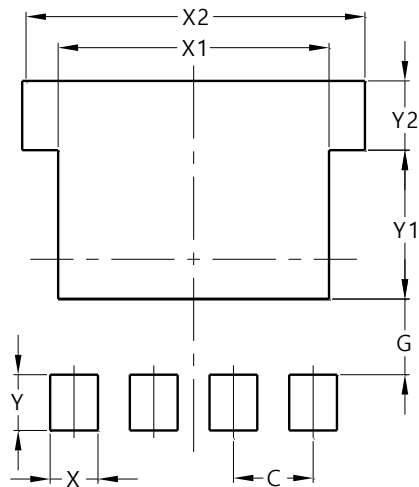


PowerDI8080-5			
Dim	Min	Max	Typ
A	1.50	1.70	--
A1	0.00	0.15	--
A3	--	--	0.25
b	0.90	1.10	--
b2	7.10	7.30	--
c	0.18	0.24	--
c2	0.47	0.57	--
D	6.10	6.30	--
D1	4.90	5.10	--
E	7.90	8.10	--
E1	6.70	6.90	--
e	--	--	2.00
H	7.80	8.10	--
L	0.60	0.80	--
L2	0.90	1.30	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI8080-5



Dimensions	Value (in mm)
C	2.00
G	1.90
X	1.20
X1	6.80
X2	8.60
Y	1.40
Y1	3.74
Y2	1.76

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